17319

13141 3 Hours / 100 Marks Seat No.

Instructions - (1) All Questions are Compulsory.

- (2) Answer each next main Question on a new page.
- (3) Illustrate your answers with neat sketches wherever necessary.
- (4) Figures to the right indicate full marks.
- (5) Assume suitable data, if necessary.

Marks

12

1. a) Attempt any <u>SIX</u> of the following:

- i) Name operating regions of a transistor.
- ii) Define the term stability factor.
- iii) Define the following terms:
 - 1) Gain
 - 2) Bandwidth
- iv) State the types of MOSFETS and draw their symbols.
- v) Define tuned amplifier.
- vi) Define efficiency of power amplifier.
- vii) Draw the schematic symbol of:
 - 1) N-Channel JFET
 - 2) P-Channel JFET.
- viii) Define intrinsic stand off ratio.

	b)	Attempt any <u>TWO</u> of the following:	08
		i) Explain the operating principle of PNP transistor.	
		ii) Explain the concept of DC load line.	
		iii) Define the following:	
		1) Load regulation	
		2) Line regulation	
2.		Attempt any FOUR of the following:	16
	a)	What is thermal runaway in transistor ? How it can be avoided ?	
	b)	Explain with a neat circuit voltage divider bias method for biasing a transistor.	
	c)	Draw the drain characteristics of JFET and explain about pinch off region and ohmic region.	
	d)	Draw and explain Input and Output characteristics of CB configuration.	
	e)	State the meaning of positive and negative feedback.	
	f)	Give four important features of IC 723 and list two applications of IC 723.	
3.		Attempt any FOUR of the following:	16
	a)	Define α and β of transistor and derive the relation between α and β .	
	b)	Describe the self biased method for FET with a neat circuit diagram.	
	c)	Draw the bootstrap sweep circuit and explain it with	

- waveforms.
- d) Compare the different types of coupling (RC coupling, Transformer coupling and Direct coupling). (Any four points).
- e) Construct a dual power supply capable of giving $\pm 15V$ using 78XX and 79XX series IC's.
- f) Define a regulator ? Explain the need of regulator.

4.

Marks

16

Attempt any FOUR of the following: a) With the help of diagram explain the working of N-Channel JFET. b) Draw the circuit diagram of single stage CE amplifier and state the function of each component. c) Describe construction and operation of E-MOSFET. d) Compare class A, class B and class C power amplifier (any four points).

- e) Explain class B push pull amplifier with a neat circuit diagram.
- f) Explain UJT relaxation oscillator with circuit diagram and waveforms.

5. Attempt any <u>FOUR</u> of the following:

16

- a) Compare CE, CB and CC configuration (any 4 points).
- b) State the Barkhausen criterion for the generation of sustained oscillations.
- c) Draw transformer coupled class A power amplifier.
- d) Draw common source FET amplifier. Describe its operation.
- e) State the advantages and disadvantages of crystal oscillator ?
- f) Draw the block diagram of DC power supply. Explain the function of each block.

16

6. Attempt any <u>FOUR</u> of the following:

- a) Explain base biasing with emitter feedback network.
- b) Explain how zener diode is used as voltage regulator.
- c) State the effect of negative feedback on following parameters:
 - i) Bandwidth
 - ii) Noise
 - iii) Gain and
 - iv) Stability.
- d) Draw circuit diagram of single tuned amplifier with frequency response curve.
- e) A phase shift oscillator has $R = 220k\Omega$ and C = 500PF. Calculate the frequency of sine wave generated by the oscillator.
- f) Explain the construction of UJT and draw its symbol.

3 Hours / 100 Marks